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STMicroelectronics 2STA1694

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High power PNP epitaxial planar bipolar transistor

Features

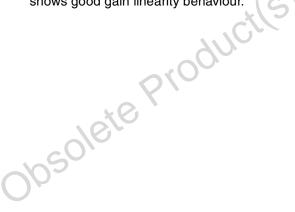
- High breakdown voltage V_{CEO} = -120 V
- Complementary to 2STC4467
- Fast-switching speed
- Typical f_t = 20 MHz
- Fully characterized at 125 °C

Applications

■ Audio power amplifier

Description

The device is a PNP transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.



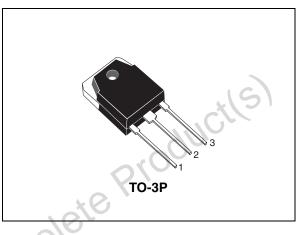


Figure 1. Internal schematic diagram

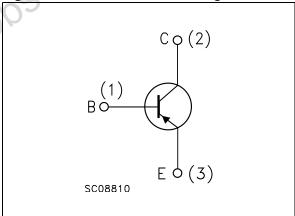


Table 1. Device summary

Order code	Marking	Package	Packaging
2STA1694	2STA1694	TO-3P	Tube

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Electrical ratings

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Electrical ratings 1

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-120	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-120	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-6	V
۱ _C	Collector current	-8	А
I _{CM}	Collector peak current (t _P < 5 ms)	-16	Α
P _{TOT}	Total dissipation at $T_c = 25 \ ^{\circ}C$	80	w
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C
Table 3.	Thermal data	· •	

Table 3. Thermal data

		incinal data	XV		
	Symbol	Parameter	10,0	Value	Unit
	R _{thj-case}	Thermal resistance junction-case	max	1.563	°C/W
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		, ICr			
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Electrical characteristics

2 Electrical characteristics

(T_{case} = 25 °C; unless otherwise specified)

Table 4.		0				
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current $(I_E = 0)$	V _{CB} = -120 V			-10	μA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = -6 V			-10	μΑ
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage (I _B = 0)	I _C = -50 mA	-120			V
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	l _C = -100 μA	-120	00		V
V _{(BR)EBO} ⁽¹⁾	Emitter-base breakdown voltage (I _C = 0)	I _E = -1 mA	-6			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = -3 A I _B = -300 mA			-1.5	V
h _{FE}	DC current gain	$I_{C} = -3 A$ $V_{CE} = -4 V$	70		140	
f _T	Transition frequency	$I_{C} = -0.5 \text{ A} \text{ V}_{CE} = -12 \text{ V}$		20		MHz

1. Pulsed duration = 300 μs, duty cycle ≤ 1.5%

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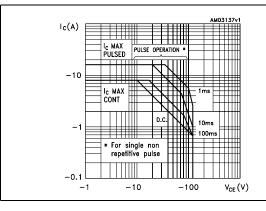
Figure 3.

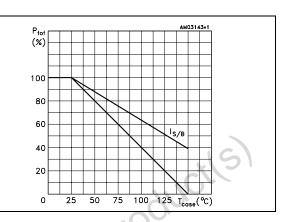
Electrical characteristics

2STA1694

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

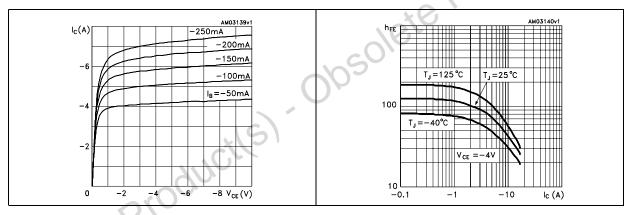


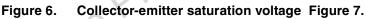


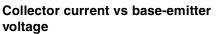
Derating curve

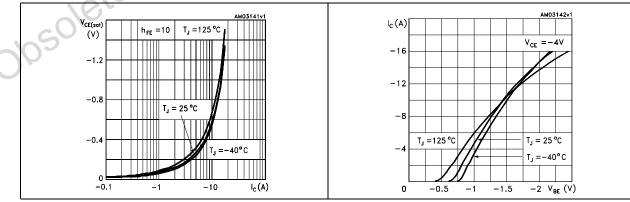


Figure 5. DC current gain









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Package mechanical data

3 Package mechanical data

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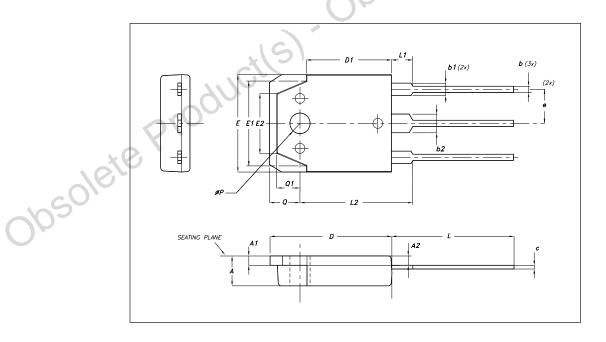
Obsolete Product(s). Obsolete Product(s)



Package mechanical data

2STA1694

рім. —	54151	mm.	MAY
	MIN.	ТҮР	MAX.
A	4.6		5
A1	1.45	1.50	1.65
A2	1.20	1.40	1.60
b	0.80	1	1.20
b1	1.80		2.20
b2	2.80		3.20
с	0.55	0.60	0.75
D	19.70	19.90	20.10
D1		13.90	
E	15.40		15.80
E1		13.60	
E2		9.60	
e	5.15	5.45	5.75
L	19.50	20	20.50
L1		3.50	· C.
L2	18.20	18.40	18.60
P	3.10		3.30
Q		5	
Q1		3.80	





Revision history

4 Revision history

Table 5. Document revision history

23-Nov-2007	Revision	Changes
23-1100-2007	1	Initial release
15-May-2008	2	Document status promoted from preliminary data to datasheet.
09-Feb-2009	3	Added section 2.1: Electrical characteristics (curves).
		Added section 2.1: Electrical characteristics (curves).



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